AMERICAN INTERNATIONAL UNIVERSITY-BANGLADESH

Faculty of Science and Technology



Assign./Case Title:	Construction of Diode and Transistor Logic Gates				
Assign./Case No:	Final LAB 6		Date of Submission:	30 March 2022	
Course Title:	DIGITAL LOGIC AND CIRCUITS LAB				
Course Code:	EEE3102		Section:	Н	
Semester:	Spring	2021-22	Degree Program:	BSc [CSE]	
Course Teacher:	NADIA ANAM				

Declaration and Statement of Authorship:

- 1. I/we hold a copy of this Assignment/Case-Study, which can be produced if the original is lost/damaged.
- 2. This Assignment/Case-Study is my/our original work and no part of it has been copied from any other student's work or from any other source except where due acknowledgement is made.
- 3. No part of this Assignment/Case-Study has been written for me/us by any other person except where such collaboration has been authorized by the concerned teacher and is clearly acknowledged in the assignment.
- 4. I/we have not previously submitted or currently submitting this work for any other course/unit.
- 5. This work may be reproduced, communicated, compared and archived for the purpose of detecting plagiarism.
- 6. I/we give permission for a copy of my/our marked work to be retained by the Faculty for review and comparison, including review by external examiners.
- 7. I/we understand that Plagiarism is the presentation of the work, idea or creation of another person as though it is your own. It is a form of cheating and is a very serious academic offence that may lead to expulsion from the University. Plagiarized material can be drawn from, and present edit, written, graphic and visual form, including electronic data, and oral presentations. Plagiarism occurs when the origin of the material used is not appropriately cited.
- 8. I/we also understand that enabling plagiarism is the act of assisting or allowing another person to plagiarize or to copy my/our work.
- * Student(s) must complete all details except the faculty use part.
- ** Please submit all assignments to your course teacher or the office of the concerned teacher.

Group Name/No.: 5

No	Name	ID	Signature
1.	Mehenaz Tabassoom	19-41398-3	
2.	Mushfiq Anjum Rafi	19-41757-3	
3.	Nadim Ahmed	19-41770-3	
4.	Fardin Rahman	19-41789-3	
5.	Md. Raihanul Islam Rafi	19-41790-3	

Faculty use only		
FACULTY COMMENTS		
	Marks Obtained	
	Total Marks	



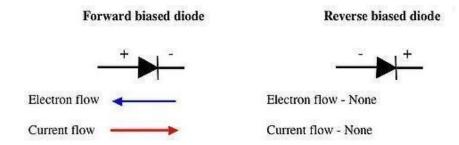
American International University- Bangladesh Department of Faculty of Engineering

EEE 3102: Digital Logic & Circuits Laboratory

Title: Construction of Diode and Transistor Logic Gates

Part I: Construction of Diode Logic Gates Introduction:

A diode is a two-terminal electrical device that allows current to flow in one direction but not the other. It is like a pipe with an internal valve that allows water to flow freely in one direction but shuts down if the water tries to flow backward. The diode's two terminals are called the anode and cathode. In the diode symbol, the arrow points from the anode (flat part of triangle) toward the cathode (point of the triangle).



The device operates by allowing current to flow from anode to cathode, basically in the direction of the triangle. Recall that current is defined to flow from the more positive voltage toward the more negative voltage (electrons flow in the opposite direction). If the diode's anode is at a higher voltage than the cathode, the diode is said to be forward biased, its resistance is very low, and current flows. If the anode is at a lower voltage than the cathode, the diode is reverse-biased, its resistance is very high, and no current flows. The diode is not a perfect conductor, so there is a small voltage drop, approximately 0.7 V, across it.

In this group of experiments we will implement some logic functions using the DL circuits and discover the potential benefits and problems of using the DL logic.

Theory and Methodology:

Diode Logic OR Gate:

A Diode Logic OR gate consists of nothing more than diodes (one for each input signal) and a resistor. Here, the $10K\Omega$ resistor (R) is added to provide a ground reference for the output signal. If there are no input signals connected to the diodes, the output will be ground, or logic 0. Thus, an open input is equivalent to a logic 0 input, and will have no effect on the operation of the rest of the circuit.

It is possible to add any number of input diodes to this circuit, each with its separate input signal. © Dept. of EEE, Faculty of Engineering, American International University-

However, two inputs are quite sufficient to demonstrate the operation of the circuit.

Assuming the diodes are ideal, the voltage truth table as given in Table 1(a) is obtained. The corresponding logic truth table is given in Table 1(b):

V _A (volt)	V _B (volt)	V _Y (volt)	A	В	Y
0	0	0	0	0	0
0	5	5	0	1	0
5	0	5	1	0	0
5	5	5	1	1	1
(a)		(b)			

Table 1

Diode Logic AND Gate:

A Diode Logic AND gate consists of diodes (one for each input signal) and a resistor. As with the DL OR gate, the $10K\Omega$ resistor (R) provides a reference connection. Unlike the OR gate, however, this is a reference to +5 volts, rather than to ground. If there are no input signals connected to the diodes, the output will be +5 volts, or logic 1. Thus, an open input will not affect the rest of the circuit, which will continue to operate normally.

As with DL-OR gates, it is possible to add any number of input diodes to this circuit, each with its separate input signal. However, two inputs are quite sufficient to demonstrate the operation of the circuit.

Assuming the diodes are ideal, the voltage truth table of the above AND gate is as given in Table 2(a). The corresponding logic truth table is in Table 2(b).

V _A (volt)	V _B (volt)	V _Y (volt)	A	В	Y
0	0	0	0	0	0
0	5	0	0	1	0
5	0	0	1	0	0
5	5	5	1	1	1
	(a)			(b)	

Table 2

Two-Input DL AND -OR Gate:

After looking at both the Diode Logic (DL) OR gate and AND gate and evaluating whether their operations were within acceptable parameters, the AND and OR gates will be cascaded. The OR gate will be used to combine the outputs of two AND gates and how well this combination works will be observed.

Diode polarity:

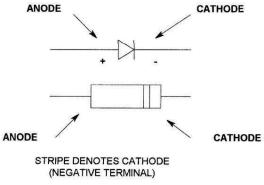


Fig: Diode polarity

Apparatus:

- (1) 10K ohm resistor (brown-black-orange).
- (2) 1N914/1N4002 diodes or equivalent.
- (3) Connecting wires.
- (4) Trainer Board

Experimental Procedure:

- 1. We have constructed the DL-OR gate on our breadboard. Then we drew a Truth Table similar to the one provided and fill in our experimental results.
- 2. We have constructed the DL-AND gate on our breadboard. Then we drew a Truth Table similar to the one provided and fill in our experimental results.
- 3. We have constructed the DL-AND-OR gate on our breadboard. Before beginning the experiment, we have calculated our expected results for all the different input combinations and put them

in a Truth Table similar to the one provided. Then we drew a second Truth Table and fill it with our experimental output values.

Results and Discussion:

When one or both inputs are set to logic high "1," current flows through one or both diodes. This current flows through the resistor, causing a voltage to appear across its terminals and resulting in a logic "1" on the output. Only when both inputs are in logic "0" do we get logic "0" on the output. The diodes do not conduct in this case, and no current flows through the resistor R. When both inputs are set to logic "1," the diodes are reverse biased and no current flows to ground. Because there is no voltage drop across the resistor R, the output is logic "1." If one of the inputs is logic "0," current flows through the corresponding diode and resistor. As a result, the diode anode (the output) will be logic "0." This method works well when the circuits are simple, but there are issues when we need to connect such gates.

Part 2: Construction of Bipolar Transistor Logic Gate

Introduction:

A bipolar transistor is a three-terminal semiconductor device. Under the control of one of the terminals, called the base, current can flow selectively from the collector terminal to the emitter terminal. In this experiment we examine how to build logic gates from bipolar transistors using the RTL, DTL and TTL design.

Theory and Methodology:

Resistor-Transistor Logic (RTL):

Resistor-Transistor Logic (RTL) is a large step beyond Diode Logic (DL). Basically, RTL replaces the diode switch with a transistor switch. If a +5v signal (logic 1) is applied to the base of the transistor (through an appropriate resistor to limit base-emitter forward voltage and current), the transistor turns fully on and grounds the output signal. If the input is grounded (logic 0), the transistor is off and the output signal is allowed to rise to +5 volts. In this way, the transistor not only inverts the logic sense of the signal, but it also ensures that the output voltage will always be a valid logic level under all circumstances. Because of this, RTL circuits can be cascaded indefinitely, where DL circuits cannot be cascaded reliably at all.

Diode-Transistor Logic:

Diode—Transistor Logic (DTL) is a class of digital circuits built from bipolar junction transistors (BJT), diodes and resistors; it is the direct ancestor of transistor—transistor logic (TTL).

DTL offers better noise margins and greater fan-outs than RTL, but suffers from low speed (especially in comparison to TTL).

RTL allows the construction of NOR gates easily, but NAND gates are relatively more difficult to get from RTL. DTL, however, allows the construction of simple NAND gates from a single transistor, with the help of several diodes and resistors.

Transistor-Transistor Logic:

We can think of a bipolar transistor as two diodes placed very close together, with the point between the diodes being the transistor base. Thus, we can use transistors in place of diodes to obtain logic gates that can be implemented with transistors and resistors only; this is called transistor-transistor logic (TTL).

One problem that DTL doesn't solve is its low speed, especially when the transistor is being turned off. Turning off a saturated transistor in a DTL gate requires it to first pass through the active region before going into cut-off. Cut-off, however, will not be reached until the stored charge in its base has been removed. The dissipation of the base charge takes time if there is no available path from the base to ground. This is why some DTL circuits have a base resistor that's tied to ground, but even this requires some trade-offs. Another problem with turning off the DTL output transistor is the fact that the effective capacitance of the output needs to charge up through Rc before the output voltage rises to the final logic '1' level, which also consumes a relatively large amount of time. TTL, however, solves the speed problem of DTL elegantly.

BJT pin configuration:



- Apparatus:
 1. 2N4124 NPN silicon transistor (or equivalent).
 2. Resistors $15K\Omega$, $1K\Omega$, $4.7 K\Omega$

- 4. Connecting wires.
- 5. Trainer Board

Experimental Procedure:

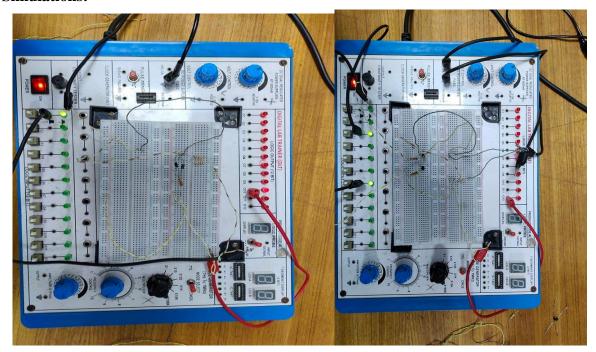
- (1) We set up the circuit for RTL inverter.
- (2) For each input combination, we found the output and place them in a Truth Table. The Truth Table have two sets of outputs- one ideal and one experimental.
- (3) We have repeated steps 1 and 2 for each circuit.

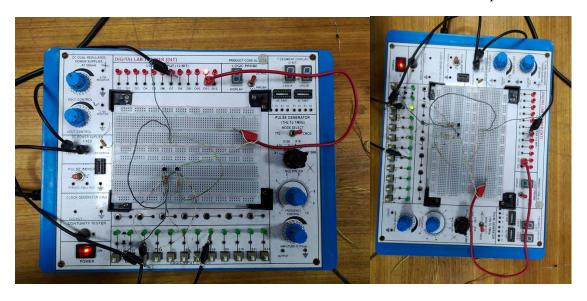
Results and Discussion:

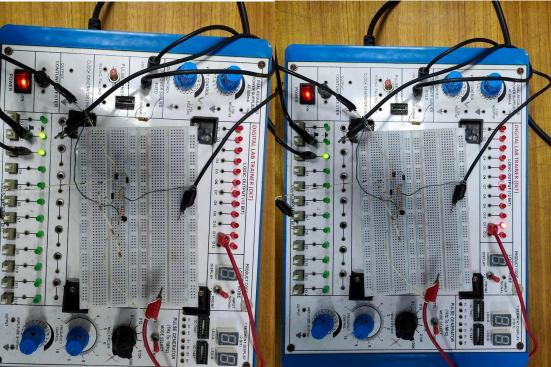
TTL (transistor-transistor logic) is a type of digital circuit made up of bipolar junction transistors (BJTs) and resistors. It is called transistor-transistor logic because transistors perform both the logic gating function (e.g., AND) and the amplifying function (contrast this with RTL and DTL).

TTL is notable for being a widely used integrated circuit (IC) family in a wide range of applications including computers, industrial controls, test equipment and instrumentation, consumer electronics, synthesizers, and so on. TTL is sometimes used to refer to TTL-compatible logic levels even when it is not directly associated with TTL integrated circuits, such as a label on the inputs and outputs of electronic instruments.

Simulations:







Reference(s):

1. Thomas L. Floyd, *Digital Fundamentals*, 9th Edition, 2006, Prentice Hall